Notice of References Cit d

Application/Control No.

Applicant(s)/Patent Under Reexamination UCHIBORI, CHIHIRO

Examiner

Granvill D Lee, Jr

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U.S. PATENT DOCUMENTS

*		Document Number Country Code-Number-Kind Code	Date MM-YYYY	Name	Classification
	4	US-4751349	10-1986	Kim et al.	174/68.5
	В	US-6249055	02-1998	Dubin	257/758
	С	US-6284656	08-1998	Farrar	438/687
	D	US-5677244	05-1996	Venkatraman	437/198
•	Е	US-5539256	02-1995	Mikagi	257/763
	F	US-5895231	10-1997	Choi et al.	438/106
	G	US-			
	н	US-			
	ı	US-			
	J	US-			
	К	US-			
	L	US-			
	М	US-			

FOREIGN PATENT DOCUMENTS

*		Document Number Country Code-Number-Kind Code	Date MM-YYYY	Country	Name	Classification
	N					
	0					
	Р					
	Q					
	R					
	S					
	Т					

NON-PATENT DOCUMENTS

*		Include as applicable: Author, Title Date, Publisher, Edition or Volume, Pertinent Pages)				
	U	Berti et al. "Characterization of a PVD-TiN as the diffusion barrier/adhesion promoter" Sematech Research pg. 118-119				
	V	Moussavi et al. "Comparison of barrier materials and deposition process ofr copper integration" IEEE IITC 98-295 0-7803-4285-2/98 pg. 295-297.				
	w	Baumann et al. "Tin/W double layers as a barrier system for use in Cu metalization" Materials for advanced metallization pg. 128-129				
	x					

*A copy of this reference is not being furnished with this Office action. (See MPEP § 707.05(a).)

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